

SGM3157 4.5Ω, Low Voltage SPDT Analog Switch in 6-Pin SC70

GENERAL DESCRIPTION

The SGM3157 is a single, bidirectional, single-pole/double-throw (SPDT) CMOS analog switch that is designed to operate from a single 1.8V to 5.5V supply. It features high-bandwidth (300MHz) and low on-resistance (4.5 Ω TYP), Targeted applications for audio switching.

The SGM3157 features guaranteed on-resistance matching (0.3 Ω MAX) between switches and guaranteed on-resistance flatness over the signal range (2.3 Ω TYP). This ensures excellent linearity and low distortion when switching audio signals.

The SGM3157 is available in Green SC70-6 package.

FEATURES

Supply Voltage Range: 1.8V to 5.5V
 On-Resistance: 4.5Ω (TYP) at 5.0V

• Fast Switching Times

 t_{ON} 20ns t_{OFF} 15ns

• High Bandwidth: 300MHz

• High Off-Isolation: -51dB at 10MHz

• Rail-to-Rail Operation

• TTL/CMOS Compatible

• Break-Before-Make Switching

Extended Industrial Temperature Range:
 -40°C to +85°C

• Available in Green SC70-6 Package

APPLICATIONS

Portable Instrumentation
Battery-Operated Equipment
Computer Peripherals
Cell Phones
PDAs
MP3s



PACKAGE/ORDERING INFORMATION

MODEL PACKAGE DESCRIPTION		SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION	
SGM3157	SC70-6	-40°C to +85°C	SGM3157YC6/TR	3157	Tape and Reel, 3000	

Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

ABSOLUTE MAXIMUM RATINGS

V+, IN to GND	0.3V to 6V
Analog, Digital Voltage Range (1)	0.3V to (V ₊) + 0.3V
Continuous Current NO, NC, or COM	±50mA
Peak Current NO, NC, or COM	±80mA
Junction Temperature	+150°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (Soldering, 10s)	+260°C
ESD Susceptibility	
HBM	2000V
MM	400V

NOTE:

1. Signals on NC, NO, or COM or IN exceeding V_{+} will be clamped by internal diodes. Limit forward diode current to maximum current ratings.

RECOMMENDED OPERATING CONDITIONS

Operating Temperature Range-40°C to +85°C

OVERSTRESS CAUTION

Stresses beyond those listed may cause permanent damage to the device. Functional operation of the device at these or any other conditions beyond those indicated in the operational section of the specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

ESD SENSITIVITY CAUTION

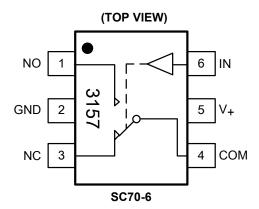
This integrated circuit can be damaged by ESD if you don't pay attention to ESD protection. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

DISCLAIMER

SG Micro Corp reserves the right to make any change in circuit design, specification or other related things if necessary without notice at any time.



PIN CONFIGURATION



PIN DESCRIPTION

PIN	NAME	FUNCTION
1	NO	Normally-Open Terminal.
2	GND	Ground.
3	NC	Normally-Closed Terminal.
4	СОМ	Common Terminal.
5	V ₊	Power Supply.
6	IN	Digital Control Pin to Connect the COM Terminal to the NO or NC Terminals.

NOTE: NO, NC and COM terminals may be an input or output.

ELECTRICAL CHARACTERISTICS

 $(V_{+} = 4.5V \text{ to } 5.5V, V_{IH} = 2.0V, V_{IL} = 0.8V, \text{ Full} = -40^{\circ}\text{C} \text{ to } +85^{\circ}\text{C}, \text{ typical values are at } V_{+} = 5.0V, T_{A} = +25^{\circ}\text{C}, \text{ unless otherwise noted.})$

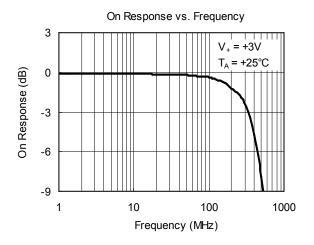
PARAMETER	SYMBOL	CONDITIONS		TEMP	MIN	TYP	MAX	UNITS
ANALOG SWITCH				•				
Analog Signal Range	V_{NO}, V_{NC}, V_{COM}		Full	0		V+	V	
On Desistance	Б	$V_{+} = 4.5V$, V_{NO} or $V_{NC} = 3.5V$,	+25°C		4.5	8	Ω	
On-Resistance	R _{ON}	I _{COM} = -10mA, Test Circuit 1					8.5	Ω
On-Resistance Match		$V_{+} = 4.5V$, V_{NO} or $V_{NC} = 3.5V$,		+25°C		0.15	0.3	Ω
Between Channels	ΔR_{ON}	I _{COM} = -10mA, Test Circuit 1	, ,				0.4	Ω
On Desistance Flatence	Б	$V_{+} = 4.5V$, V_{NO} or $V_{NC} = 1.0V$, 2	.0V, 3.5V,	+25°C		2.3	3.3	Ω
On-Resistance Flatness	R _{FLAT(ON)}	I _{COM} = -10mA, Test Circuit 1		Full			3.7	Ω
Source Off Leakage Current	I _{NC(OFF)} , I _{NO(OFF)}	V_{+} = 5.5V, V_{NO} or V_{NC} = 1.0V, 4. V_{COM} = 4.5V, 1.0V	5V,	Full			1	μΑ
Channel On Leakage Current	I _{NC(ON)} , I _{NO(ON)} , I _{COM(ON)}	V_{+} = 5.5V, V_{COM} = 1.0V, 4.5V, V_{NO} or V_{NC} = 1.0V, 4.5V, or float	ing	Full			1	μΑ
DIGITAL INPUTS					•		•	
Input High Voltage	V _{INH}			Full	1.5			V
Input Low Voltage	V _{INL}			Full			0.6	٧
Input Leakage Current	I _{IN}	V ₊ = 5.5V, V _{IN} = 0V or 5.5V	Full			1	μA	
DYNAMIC CHARACTERISTIC	S			•	•	•		
Turn-On Time	t _{on}	V_{NO} or V_{NC} = 3.0V, V_{IH} = 1.5V, V_{IH} = 1.5V, V_{IH} = 300 Ω , V_{IH} = 35pF, Test Circ		+25°C		20		ns
Turn-Off Time	t _{OFF}	V_{NO} or V_{NC} = 3.0V, V_{IH} = 1.5V, V_{RL} = 300 Ω , C_{L} = 35pF, Test Circ	/ _{IL} = 0V, cuit 2	+25°C		15		ns
Break-Before-Make Time Delay	t _D	V_{NO1} or V_{NC1} = V_{NO2} or V_{NC2} = 3\ R_L = 300 Ω , C_L = 35pF, Test Circ		+25°C		5		ns
Skew	t _{SKEW}	$R_S = 39\Omega$, $C_L = 50pF$, Test Circ	uit 4	+25°C		5		ns
Off Includion	0	$R_L = 50\Omega$, $C_L = 5pF$,	f = 10MHz	+25°C		-51		dB
Off Isolation	O _{ISO}	Signal = 0dBm, Test Circuit 5	f = 1MHz	+25°C		-72		dB
-3dB Bandwidth	BW	Signal = 0dBm, R_L = 50 Ω , C_L = 5pF, Test Circuit 6		+25°C		300		MHz
Source Off Capacitance	$C_{NC(OFF)}, C_{NO(OFF)}$	f = 1MHz	+25°C		5.5		pF	
Channel On Capacitance	$C_{NC(ON)}, C_{NO(ON)}, C_{COM(ON)}$	f = 1MHz	+25°C		15.5		pF	
POWER REQUIREMENTS								
Power Supply Range	V ₊		Full	1.8		5.5	V	
Power Supply Current	I ₊	$V_{+} = 5.5V$, $V_{IN} = 0V$ or V_{+}	Full			5	μA	

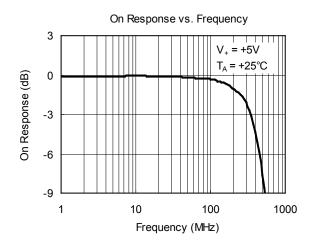
ELECTRICAL CHARACTERISTICS (continued)

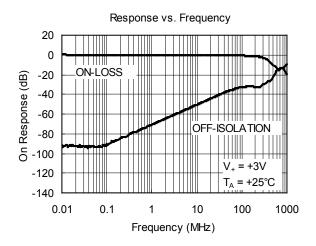
 $(V_{+} = 2.7V \text{ to } 3.6V, V_{IH} = 1.4V, V_{IL} = 0.5V, \text{ Full} = -40^{\circ}\text{C} \text{ to } +85^{\circ}\text{C}, \text{ typical values are at } V_{+} = 3.0V, T_{A} = +25^{\circ}\text{C}, \text{ unless otherwise noted.})$

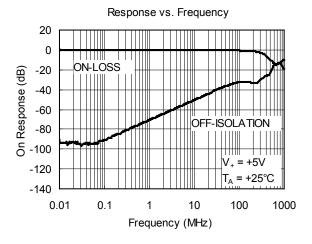
PARAMETER	SYMBOL	CONDITIONS		TEMP	MIN	TYP	MAX	UNITS
ANALOG SWITCH				•		•		
Analog Signal Range	V_{NO}, V_{NC}, V_{COM}			Full	0		V+	V
On-Resistance	R _{ON}	$V_{+} = 2.7V, V_{NO} \text{ or } V_{NC} = 1.5V,$	$V_{+} = 2.7 \text{V}, V_{NO} \text{ or } V_{NC} = 1.5 \text{V},$			7	10	Ω
On-Resistance	Kon	I _{COM} = -10mA, Test Circuit 1	I _{COM} = -10mA, Test Circuit 1				10.5	Ω
On-Resistance Match	ΔR_{ON}	$V_{+} = 2.7V$, V_{NO} or $V_{NC} = 1.5V$,		+25°C		0.15	0.3	Ω
Between Channels	ΔNON	I _{COM} = -10mA, Test Circuit 1		Full			0.4	Ω
On-Resistance Flatness	$V_{+} = 2.7V, V_{NO} \text{ or } V_{NC} = 1.0V, 1.5V, 2.0V,$		+25°C		3	4	Ω	
On-registance riatiless	R _{FLAT(ON)}	I _{COM} = -10mA, Test Circuit 1		Full			4.3	Ω
Source Off Leakage Current	I _{NC(OFF)} , I _{NO(OFF)}	V_{+} = 3.6V, V_{NO} or V_{NC} = 0.3V, 3. V_{COM} = 3.3V, 0.3V,	3V,	Full			1	μΑ
Channel On Leakage Current	I _{NC(ON)} , I _{NO(ON)} , I _{COM(ON)}	V_{+} = 3.6V, V_{COM} = 0.3V, 3.3V, V_{NO} or V_{NC} = 0.3V, 3.3V, or float	ting	Full			1	μA
DIGITAL INPUTS								
Input High Voltage	V _{INH}			Full	1			V
Input Low Voltage	V _{INL}			Full			0.5	V
Input Leakage Current	I _{IN}	$V_{+} = 5.5V$, $V_{IN} = 0V$ or 3.6V	Full			1	μA	
DYNAMIC CHARACTERISTIC	s							
Turn-On Time	ton	V_{NO} or V_{NC} = 1.5V, V_{IH} = 1.5V, V_{RL} = 300 Ω , C_L = 35pF, Test Cir		+25°C		30		ns
Turn-Off Time	t _{OFF}	V_{NO} or V_{NC} = 1.5V, V_{IH} = 1.5V, V_{RL} = 300 Ω , C_L = 35pF, Test Cir	V _{IL} = 0V, cuit 2	+25°C		25		ns
Break-Before-Make Time Delay	t _D	V_{NO1} or V_{NC1} = V_{NO2} or V_{NC2} = 3' R_L = 300 Ω , C_L = 35pF, Test Cir		+25°C		8		ns
Skew	t _{SKEW}	$R_S = 39\Omega$, $C_L = 50pF$, Test Circ	uit 4	+25°C		2		ns
Off lookstion	0	$R_L = 50\Omega$, $C_L = 5pF$,	f = 10MHz	+25°C		-51		dB
Off Isolation	O _{ISO}	Signal = 0dBm, Test Circuit 5	f = 1MHz	+25°C		-72		dB
-3dB Bandwidth	BW	Signal = 0dBm, R_L = 50 Ω , C_L = 5pF, Test Circuit 6		+25°C		300		MHz
Source Off Capacitance	$C_{NC(OFF)}, C_{NO(OFF)}$	f = 1MHz	+25°C		5.5		pF	
Channel On Capacitance	$C_{\text{NC(ON)}}, C_{\text{NO(ON)}}, \ C_{\text{COM(ON)}}$	f = 1MHz	+25°C		15.5		pF	
POWER REQUIREMENTS								
Power Supply Range	V ₊			Full	1.8		5.5	V
Power Supply Current	I ₊	$V_{+} = 5.5V$, $V_{IN} = 0V$ or V_{+}	$V_{+} = 5.5V$, $V_{IN} = 0V$ or V_{+}				5	μΑ

TYPICAL PERFORMANCE CHARACTERISTICS

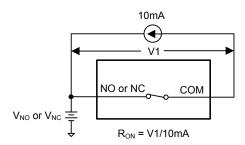




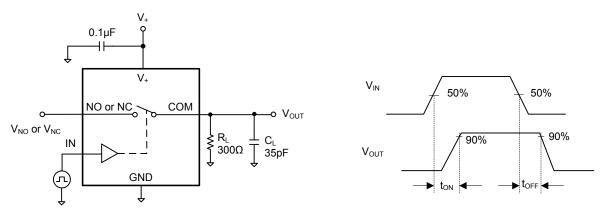




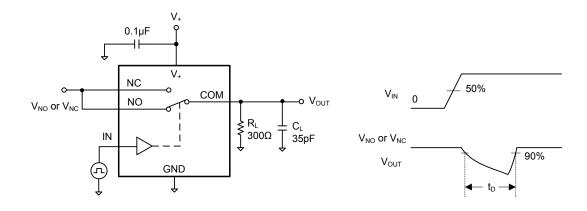
TEST CIRCUITS



Test Circuit 1. On-Resistance

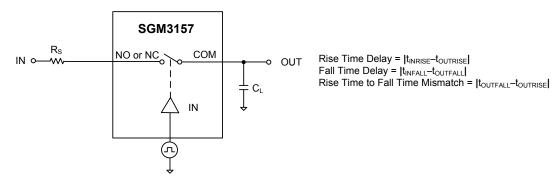


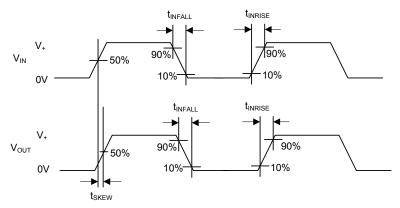
Test Circuit 2. Switching Times



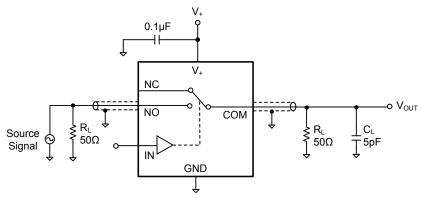
Test Circuit 3. Break-Before-Make Time Delay, t_D

TEST CIRCUITS (continued)

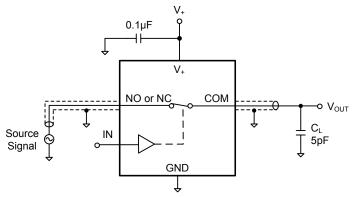




Test Circuit 4. Output Signal Skew



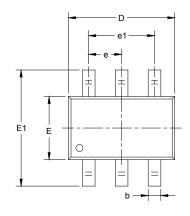
Test Circuit 5. Off Isolation

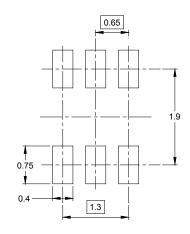


Test Circuit 6. -3dB Bandwidth

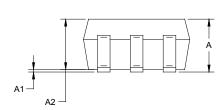


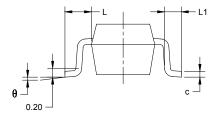
PACKAGE OUTLINE DIMENSIONS SC70-6





RECOMMENDED LAND PATTERN (Unit: mm)

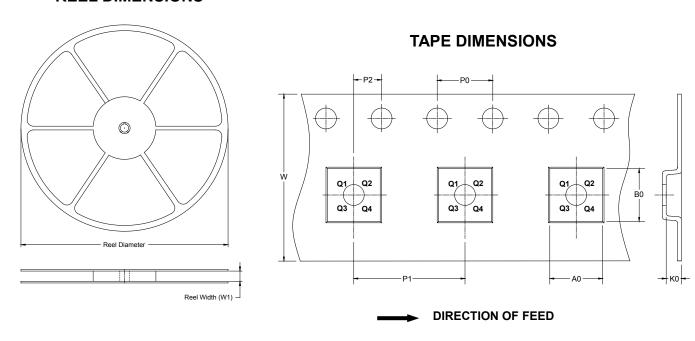




Symbol		nsions meters	Dimensions In Inches			
	MIN	MAX	MIN	MAX		
Α	0.900	1.100	0.035	0.043		
A1	0.000	0.100	0.000	0.004		
A2	0.900	1.000	0.035	0.039		
b	0.150	0.350	0.006	0.014		
С	0.080	0.150	0.003	0.006		
D	2.000	2.200	0.079	0.087		
E	1.150	1.350	0.045	0.053		
E1	2.150	2.450	0.085	0.096		
е	e 0.65 TYP		0.026 TYP			
e1	1.300	BSC	0.051 BSC			
L	L 0.525 REF		0.021	REF		
L1	0.260	0.460	0.010	0.018		
θ	0°	8°	0°	8°		

TAPE AND REEL INFORMATION

REEL DIMENSIONS

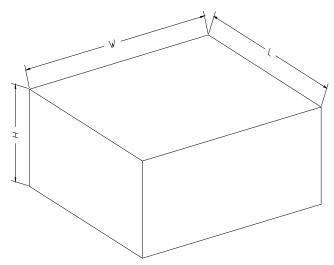


NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
SC70-6	7"	9.5	2.40	2.50	1.20	4.0	4.0	2.0	8.0	Q3

CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton
7" (Option)	368	227	224	8
7"	442	410	224	18